TPS792 Ultra-Low Noise, High-PSRR, Fast RF, 100mA, Low-Dropout Linear Regulator

1 Features

- For a more updated portfolio device, see the TPS7A20
- 100mA low-dropout regulator with enable
- Available in fixed-voltage versions and adjustable
- Low noise:
  - 50μV_{RMS} (legacy chip)
  - 69μV_{RMS} (new chip)
- Fast start-up time:
  - 50µs (legacy chip)
  - 500µs (new chip)
- Very-low dropout voltage: 55mV (typ)

2 Applications

- TV applications
- Building automation
- Smartphones and tablets
- Connected peripherals and printers
- Home theater and entertainment applications

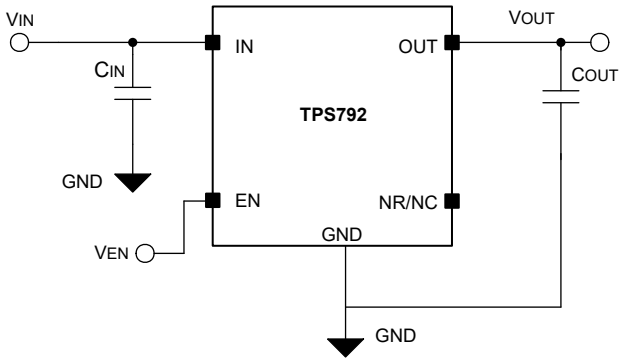
3 Description

The TPS792 is a low-dropout (LDO) voltage regulators that features high power-supply rejection ratio (PSRR), and offers excellent line and load transient responses. This device is stable with a small 2.2µF ceramic capacitor on the output. The TPS792 offers low dropout voltages for example, 55mV (typical) at 100mA. The low output noise and great PSRR makes this device suitable to power sensitive analog loads. The TPS792 offers a flexible option for post regulation with its adjustable capability.

Package Information

PART NUMBER	PACKAGE(1)	PACKAGE SIZE(2)
TPS792	DBV (SOT-23, 6)	2.9mm × 2.8mm
	DBV (SOT-23, 5)	2.9mm × 2.8mm

(1) For more information, see the *Mechanical, Packaging, and Orderable Information*.
(2) The package size (length × width) is a nominal value and includes pins, where applicable.



Typical Application Circuit

An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.

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4 Pin Configuration and Functions

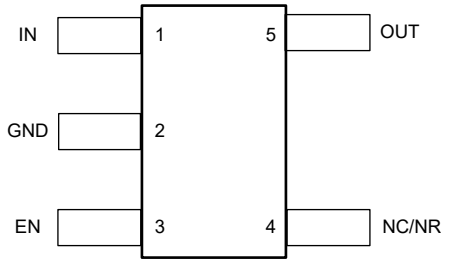


Figure 4-1. DBV Package, 5-Pin SOT-23 Fixed Voltage Version (Top View)

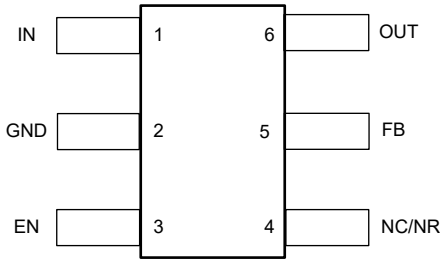


Figure 4-2. DBV Package, 6-Pin SOT-23 Adjustable Voltage Version (Top View)

Table 4-1. Pin Functions

PIN			I/O	DESCRIPTION
NAME	DBV	YZQ		
EN	3	A3	I	Enable pin. Driving the enable pin (EN) high turns on the regulator. Driving this pin low puts the regulator into shutdown mode. EN can be connected to IN if not used.
FB	5	—	I	Feedback pin. This terminal is the feedback input pin for the adjustable device. Fixed voltage versions in the DBV package do not have this pin.
GND	2	A1	—	Regulator ground.
IN	1	C3	I	Input to the device.
NR/NC	4	B2	—	Noise Reduction pin (legacy chip only). Connecting an external capacitor to this pin filters noise generated by the internal bandgap. This configuration improves power-supply rejection and reduces output noise for the legacy chip and YZQ package only. No Connect pin (new chip only). This pin is not internally connected. Connect to GND for improved thermal performance or leave floating. For lower noise performance on a fixed device, consider looking at the TPS7A20.
OUT	6	C1	O	Output of the regulator.

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5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

		MIN	MAX	UNIT
Voltage	V_{IN} , V_{EN}, V_{OUT} (Legacy Chip)	–0.3	6	V
	V_{IN} , V_{EN} (New Chip)	–0.3	6.5	V
	V_{OUT} (New Chip)	–0.3	V_{IN} + 0.3 (2)	
Current	Output, I_{OUT}	Internally limited		
Temperature	Operating junction, T_J	–40	150	°C
	Storage, T_{stg}	–65	150	°C

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) The absolute maximum rating is V_{IN} + 0.3 V or 6.5 V, whichever is smaller.

5.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins(1)	±2000	V
		Charged device model (CDM), per JEDEC specification JESD22-C101, V all pins(2)	±500	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
V_{IN}	Input voltage	2.7		5.5	V
V_{EN}	Enable voltage	0		5.5	V
V_{OUT}	Output voltage	V_{FB}		5	V
I_{OUT}	Output current	0		100	mA
T_J	Operating junction temperature	–40		125	°C
C_{IN}	Input capacitor (Legacy Chip)	0.1	1		µF
	Input capacitor (New Chip)	1			
C_{OUT}	Output capacitor	2.2(1) (2)	10		µF
C_{NR}	Noise reduction capacitor(3)	0	10		nF
C_{FF}	Feed-forward capacitor (Legacy Chip)		15		pF
	Feed-forward capacitor (New Chip)(4)	0	10	100	nF
R_2	Lower feedback resistor (Legacy Chip)		30.1		kΩ
F_{EN}	Enable toggle frequency (New Chip)			10	kHz

(1) If C_{FF} is not used or V_{OUT}(nom) < 1.8V, the minimum recommended C_{OUT} = 4.7µF.
(2) The minimum effective capacitance is 0.47 µF for the new chip only.
(3) Legacy Chip only. The New Chip does not have a Noise Reduction pin. For more information please refer to Pin Functions table.
(4) Feed-forward capacitor is optional and not required for stability.

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5.4 Thermal Information

THERMAL METRIC[1]		TPS792				UNIT
		DBV (SOT23-6)	DBV (SOT23-6)[2]	DBV (SOT23-5)	DBV (SOT23-5)[2]	
		6 PINS	6 PINS	5 PINS	5 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	225.1	171.7	225.1	171.7	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	78.4	110.8	78.4	110.8	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	54.7	85.4	54.7	85.4	°C/W
ψ_{JT}	Junction-to-top characterization parameter	3.3	54.4	3.3	54.4	°C/W
ψ_{JB}	Junction-to-board characterization parameter	53.8	85.2	53.8	85.2	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	N/A	N/A	N/A	N/A	°C/W

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Packaging application note.
(2) New Chip.

5.5 Electrical Characteristics

over recommended operating temperature range, T_J = –40°C to +125°C $V_{EN} = V_{IN}$, $V_{IN} = V_{O(typ)}$ + 1V, I_{OUT} = 1 mA, C_{OUT} = 10 µF, C_{NR} = 0.01 µF (Legacy Chip) (unless otherwise noted). All typical values at T_J= 25°C.

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
V_{OUT}	Output accuracy	TPS79201 [1]	0µA < I_{OUT} < 100mA 1.22V < V_{OUT} < 5.2V	0.98 V_{OUT}	V_{OUT}	1.02 V_{OUT}	V
		TPS79225 (Legacy chip only)	0µA < I_{OUT} < 100mA 1.22V < V_{OUT} < 5.2V	2.45	2.5	2.55	V
		TPS79228 (Legacy chip only)	0µA < I_{OUT} < 100mA 1.22V < V_{OUT} < 5.2V	2.744	2.8	2.856	V
		TPS79230	0µA < I_{OUT} < 100mA, 4V < V_{IN} < 5.5V	2.94	3	3.06	
I_{GND}	Quiescent current (GND current)	0µA ≤ I_O ≤ 100mA (Legacy Chip)			170	250	µA
		0µA ≤ I_O ≤ 100mA(New Chip)			250	1000	
$\Delta V_{OUT}/\Delta I_{OUT}$	Load regulation[2]	0µA ≤ I_{OUT} ≤ 100mA			5		mV
$\Delta V_{OUT}/\Delta VIN$	Line regulation	V_{OUT} + 1V ≤ V_{IN} ≤ 5.5V			0.05	0.12	%/V
Vn	Output noise voltage (TPS7928) (Legacy chip only)	BW = 100Hz to 100kHz, I_{OUT} = 100mA	C_{NR} = 0.001µF		50		μV_{RMS}
		BW = 100Hz to 100kHz, I_{OUT} = 100mA	C_{NR} = 0.0047µF		33		
		BW = 100Hz to 100kHz, I_{OUT} = 100mA	C_{NR} = 0.01µF		31		
		BW = 100Hz to 100kHz, I_{OUT} = 100mA	C_{NR} = 0.1µF		27		
	Output noise voltage (TPS79230)	BW = 100Hz to 100kHz, I_{OUT} = 100mA	(New Chip)		69		
t_{STR}	Time, start-up (TPS79230)	R_L = 14 Ω, C_{OUT} = 1µF	C_{NR} = 0.001µF		50		µs
			C_{NR} = 0.0047µF		70		
			C_{NR} = 0.01µF		90		
			(New Chip)		500		

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5.5 Electrical Characteristics (continued)

over recommended operating temperature range, T_J = –40°C to +125°C V_{EN} = V_{IN}, V_{IN} = $V_{O(typ)}$ + 1V, I_{OUT} = 1 mA, C_{OUT} = 10 µF, C_{NR} = 0.01 µF (Legacy Chip) (unless otherwise noted). All typical values at T_J= 25°C.

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
I_{CL}	Output current limit	V_{OUT} = 0V(Legacy Chip)		285		600	mA
I_{CL}	Output current limit	V_{IN} = $V_{OUT(NOM)}$ + 1 V, V_{OUT} = 0.9 x $V_{OUT(NOM)}$ (New Chip only)		320		460	mA
I_{SC}	Short-circuit current limit	V_{OUT} = 0V (New Chip)			175		mA
I_{SHDN}	Shutdown current	V_{EN} = 0V, 2.7V < V_I < 5.5V(Legacy Chip)			0.07	1	µA
		V_{EN} = 0V, 2.7V < V_I < 5.5V(New Chip)			0.01	1	
$V_{EN(HI)}$	High-level enable input voltage	2.7V ≤ V_{IN} ≤ 5.5V		1.7		V_{IN}	V
$V_{EN(HI)}$	High-level enable input voltage	2.7V ≤ V_{IN} ≤ 5.5V (New Chip)		0.85		V_{IN}	V
$V_{EN(LOW)}$	Low-level enable input voltage	2.7V ≤ V_{IN} ≤ 5.5V		0		0.7	V
$V_{EN(LOW)}$	Low-level enable input voltage	2.7V ≤ V_{IN} ≤ 5.5V (New Chip)		0		0.425	V
I_{EN}	Enable pin current	V_{EN} = 0 V		–1		1	µA
V_{REF}	Internal reference (TPS79201)			1.201	1.225	1.25	V
PSRR	Power-supply rejection ratio (TPS79228)	f = 100Hz	I_{OUT} = 10mA (Legacy Chip)		70		dB
	Power-supply rejection ratio (TPS79230)		I_{OUT} = 10mA (New Chip)		64		
	Power-supply rejection ratio (TPS79228)		I_{OUT} = 100mA (Legacy Chip)		72		
	Power-supply rejection ratio (TPS79230)		I_{OUT} = 100mA (New Chip)		64		
	Power-supply rejection ratio (TPS79228)	f = 10kHz	I_{OUT} = 100mA (Legacy Chip)		75		
	Power-supply rejection ratio (TPS79230)		I_{OUT} = 100mA (New Chip)		49		
	Power-supply rejection ratio (TPS79228)	f = 100kHz	I_{OUT} = 100mA (Legacy Chip)		47		
	Power-supply rejection ratio (TPS79230)		I_{OUT} = 100mA (New Chip)		39		

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5.5 Electrical Characteristics (continued)

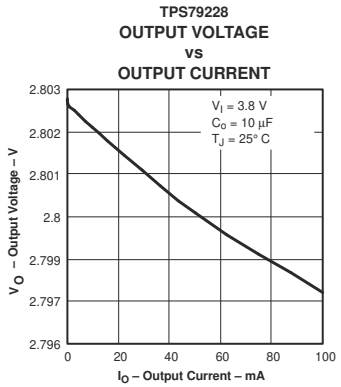
over recommended operating temperature range, T_J = –40°C to +125°C V_{EN} = V_{IN}, V_{IN} = $V_{O(typ)}$ + 1V, I_{OUT} = 1 mA, C_{OUT} = 10 µF, C_{NR} = 0.01 µF (Legacy Chip) (unless otherwise noted). All typical values at T_J= 25°C.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{DO} (3)	Dropout voltage (TPS79228)	V_{IN}= V_{OUT} - 0.1V, I_{OUT} = 100mA (Legacy Chip only)		60	110	mV
	Dropout voltage (TPS79230)	V_{IN}= V_{OUT} - 0.1V, I_{OUT} = 100mA		55	100	
V_{UVLO}	UVLO threshold	V_{IN} rising (Legacy Chip)	2.25		2.65	V
		VIN rising (New Chip)	1.32		1.6	
$V_{UVLO(HYST)}$	UVLO hysteresis	T_J = 25°C, V_{CC} rising (Legacy Chip)		100		mV
		T_J = 25°C, V_{CC} rising (New Chip)		130		

(1) The minimum IN operating voltage is 2.7 V or $V_{O(typ)}$ + 1 V, whichever is greater. The maximum IN voltage is 5.5 V. The maximum output current is 100 mA.
(2) If V_{OUT} ≤ 2.5V then $V_{IN(min)}$ = 2.7V, $V_{IN(max)}$ = 5.5V: Line regulation(mV) = (%/V) * V_{OUT} ($V_{IN(max)}$ - 2.7V) / 100 *100
(3) IN voltage equals $V_{OUT(nom)}$ – 100 mV; The TPS79225 dropout voltage is limited by the input voltage range limitations.

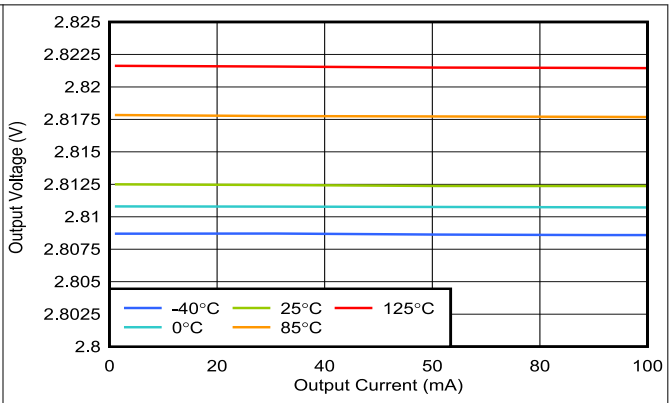
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5.6 Typical Characteristics



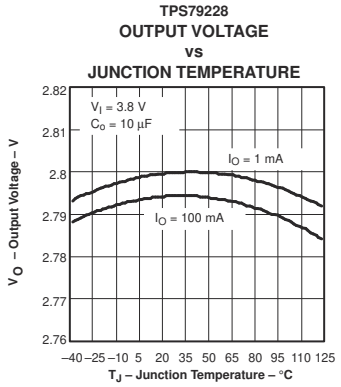
Legacy chip

Figure 5-1. TPS792 Output Voltage vs Output Current



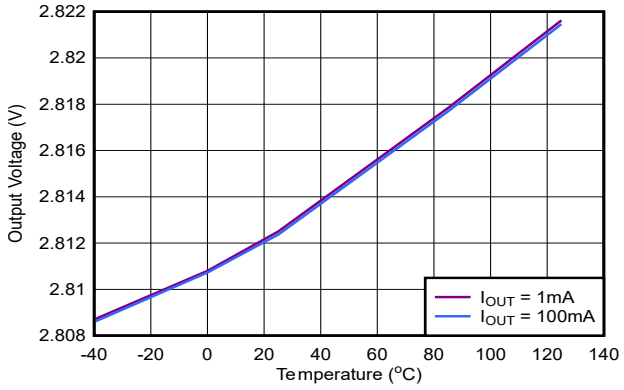
New chip

Figure 5-2. TPS792 Output Voltage vs Output Current



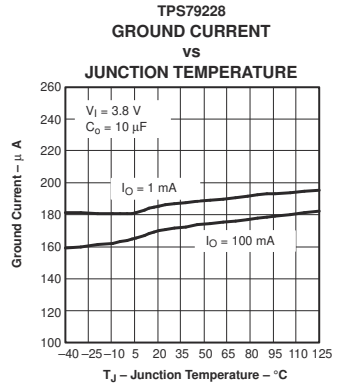
Legacy chip

Figure 5-3. TPS792 Output Voltage vs Junction Temperature



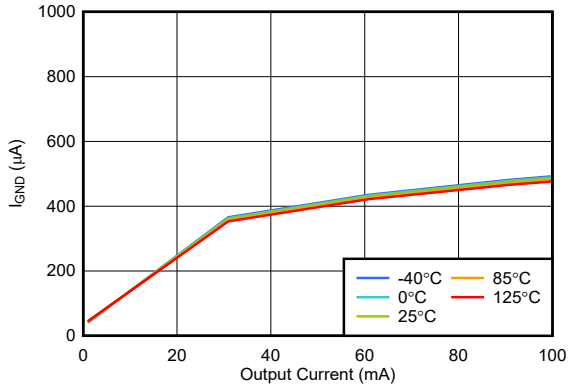
New chip

Figure 5-4. TPS792 Output Voltage vs Junction Temperature



Legacy chip

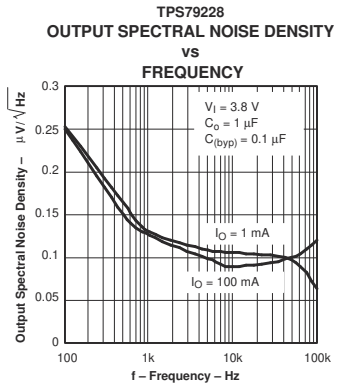
Figure 5-5. TPS792 Ground Current vs Junction Temperature



New chip

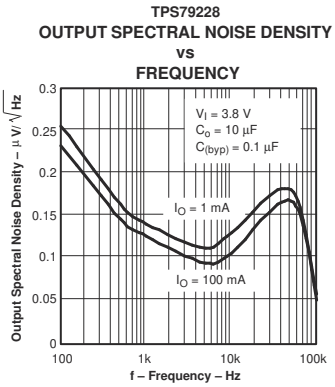
Figure 5-6. TPS792 Ground Current vs I_{OUT}

5.6 Typical Characteristics (continued)



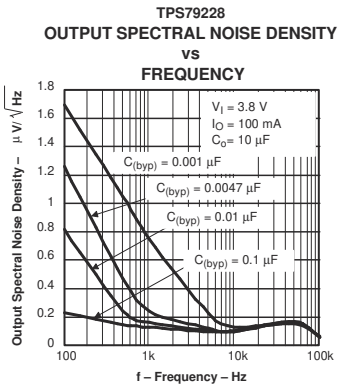
Legacy chip

Figure 5-7. TPS792 Output Spectral Noise Density vs Frequency



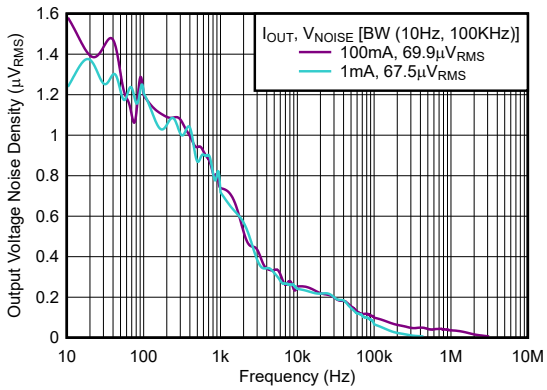
Legacy chip

Figure 5-8. TPS792 Output Spectral Noise Density vs Frequency



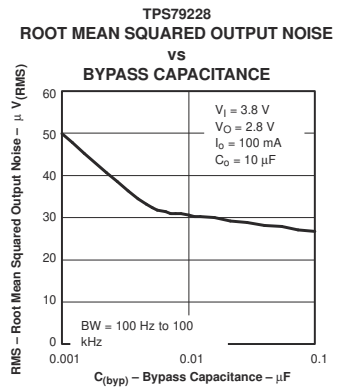
Legacy chip

Figure 5-9. TPS792 Output Spectral Noise Density vs Frequency



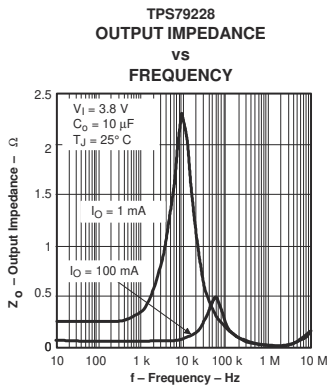
New chip

Figure 5-10. TPS792 Output Spectral Noise Density vs Frequency



Legacy chip

Figure 5-11. Root Mean Squared Output Noise vs Bypass Capacitance

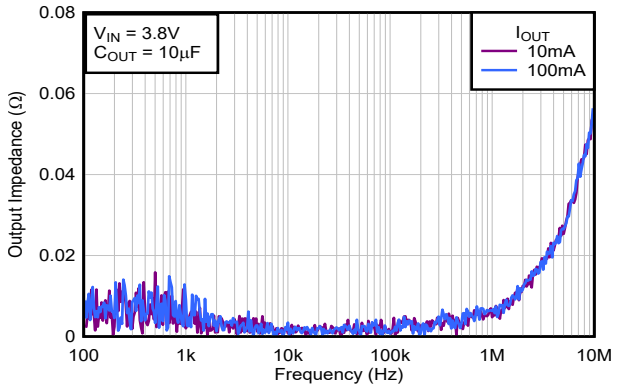


Legacy chip

Figure 5-12. Output Impedance vs Frequency

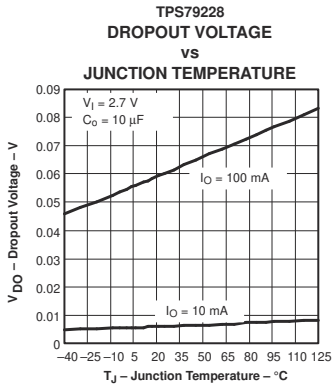
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5.6 Typical Characteristics (continued)



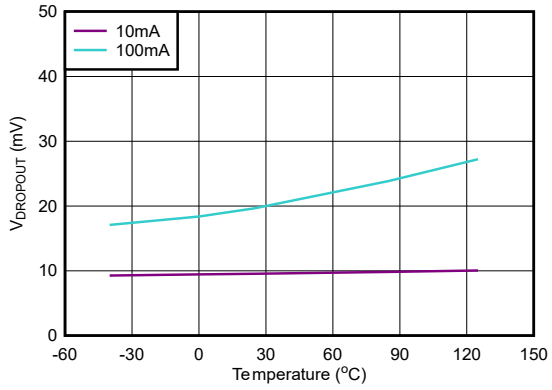
New chip

Figure 5-13. Output Impedance vs Frequency



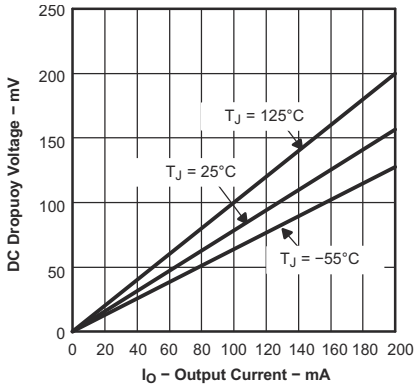
Legacy chip

Figure 5-14. TPS792 Dropout Voltage vs Junction Temperature



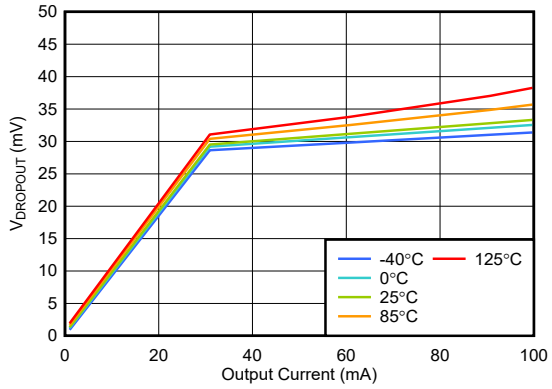
New chip

Figure 5-15. TPS792 Dropout Voltage vs Junction Temperature



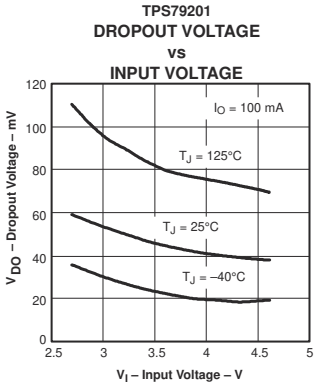
Legacy chip

Figure 5-16. Dropout Voltage vs Output Current



New chip

Figure 5-17. Dropout Voltage vs Output Current

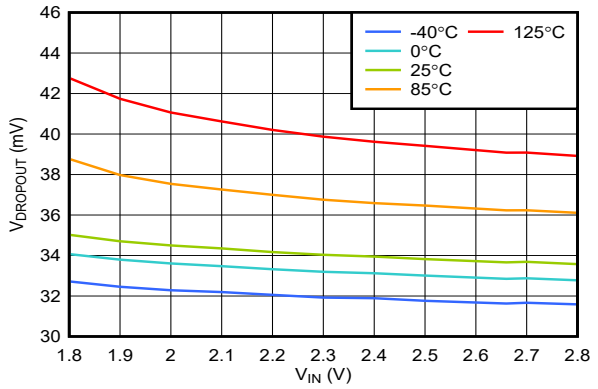


Legacy chip

Figure 5-18. TPS792 Dropout Voltage vs Input Voltage

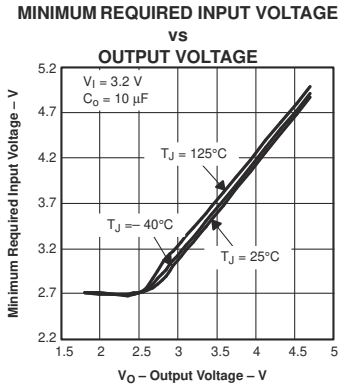
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5.6 Typical Characteristics (continued)



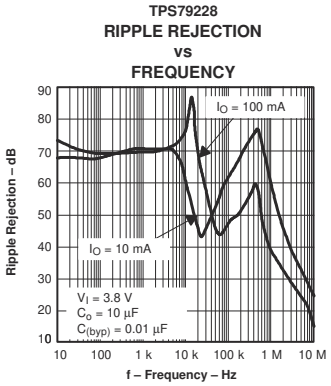
New chip

Figure 5-19. TPS792 Dropout Voltage vs Input Voltage



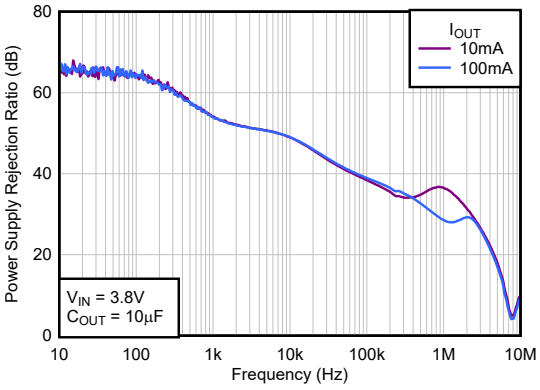
Legacy chip

Figure 5-20. Minimum Required Input Voltage vs Output Voltage



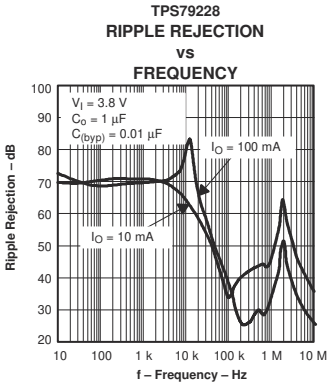
Legacy chip

Figure 5-21. TPS792 Ripple Rejection vs Frequency



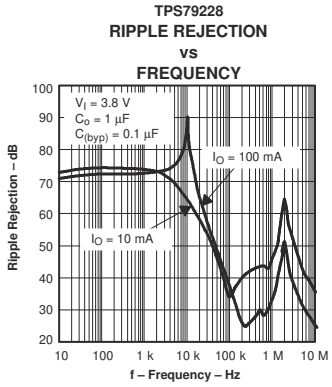
New chip

Figure 5-22. TPS792 Ripple Rejection vs Frequency



Legacy chip

Figure 5-23. TPS792 Ripple Rejection vs Frequency

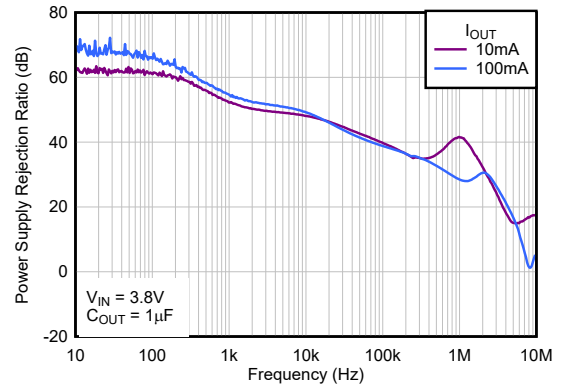


Legacy chip

Figure 5-24. TPS792 Ripple Rejection vs Frequency

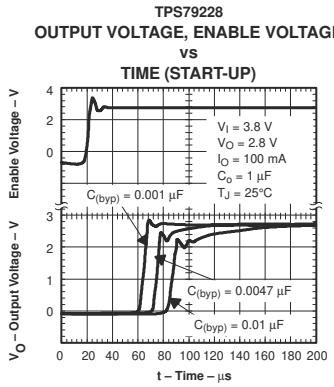
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5.6 Typical Characteristics (continued)



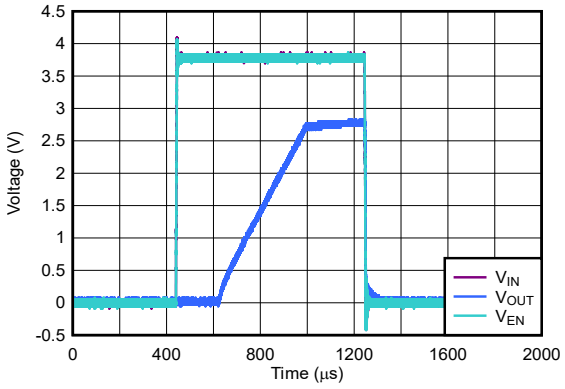
New chip

Figure 5-25. TPS792 Ripple Rejection vs Frequency



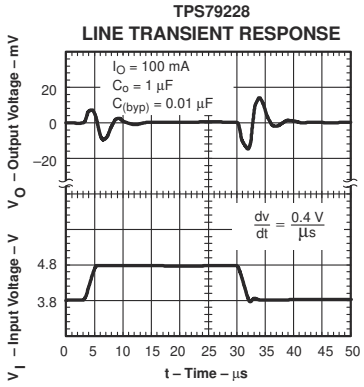
Legacy chip

Figure 5-26. TPS792 Output Voltage and Enable Voltage vs Time (Start-Up)



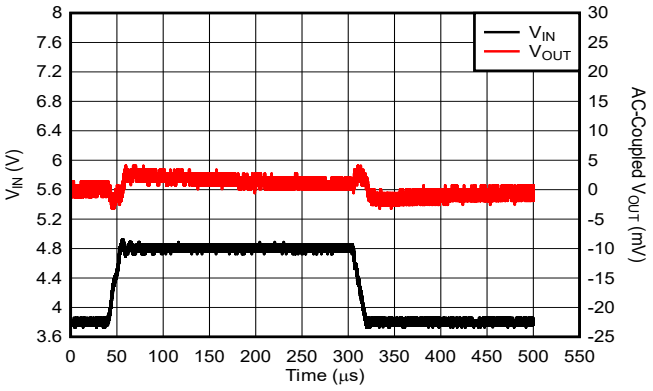
New chip

Figure 5-27. TPS792 Output Voltage and Enable Voltage vs Time (Start-Up)



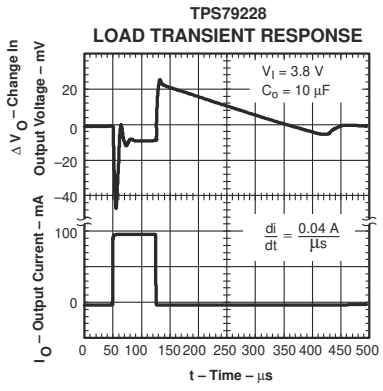
Legacy chip

Figure 5-28. TPS792 Line Transient Response



New chip

Figure 5-29. TPS792 Line Transient Response

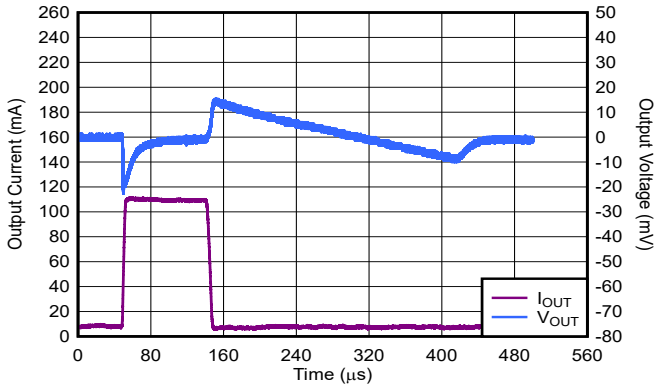


Legacy chip

Figure 5-30. TPS792 Load Transient Response

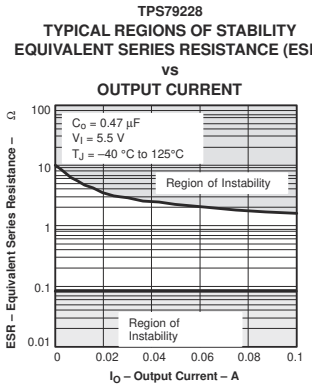
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5.6 Typical Characteristics (continued)



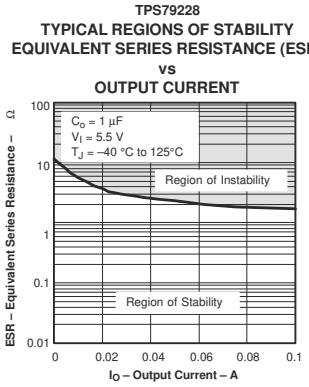
New chip

Figure 5-31. TPS792 Load Transient Response



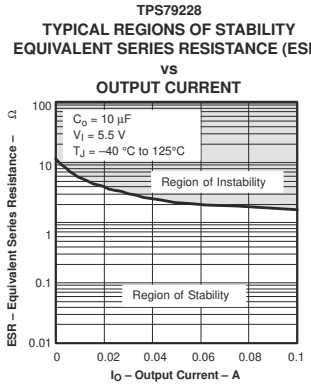
Legacy chip

Figure 5-32. Typical Regions of Stability Equivalent Series Resistance (ESR) vs Output Current



Legacy chip

Figure 5-33. Typical Regions of Stability Equivalent Series Resistance (ESR) vs Output Current



Legacy chip

Figure 5-34. Typical Regions of Stability Equivalent Series Resistance (ESR) vs Output Current

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6 Detailed Description

6.1 Overview

The TPS792xx family of LDO regulators has been optimized for use in noise-sensitive battery-operated equipment. The device features extremely low dropout voltages, high PSRR, ultra-low output noise, low quiescent current, and enable-input to reduce supply currents to less than 1µA when the regulator is turned off..

6.2 Functional Block Diagrams

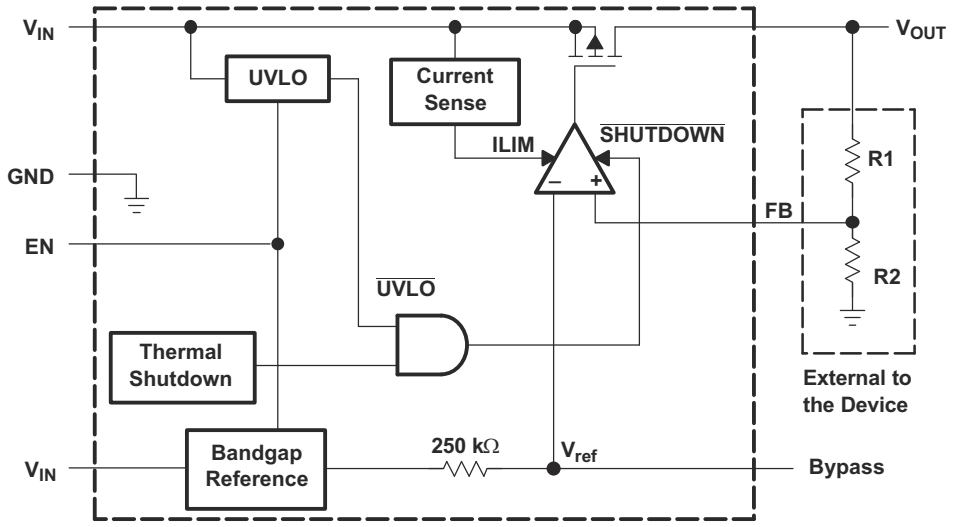


Figure 6-1. Functional Block Diagram – Adjustable Version (Legacy Chip)

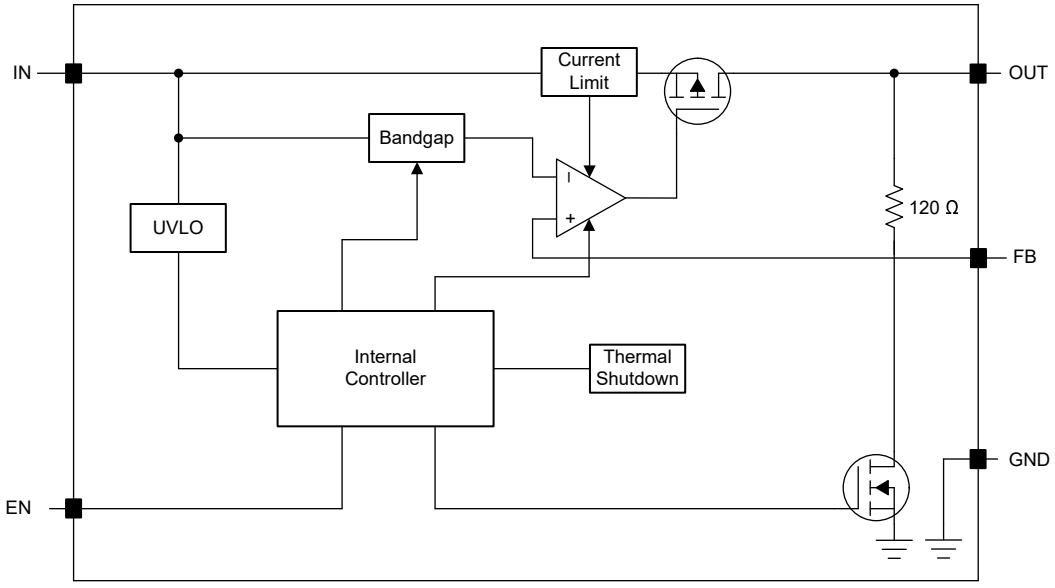


Figure 6-2. Functional Block Diagram – Adjustable Version (New Chip)

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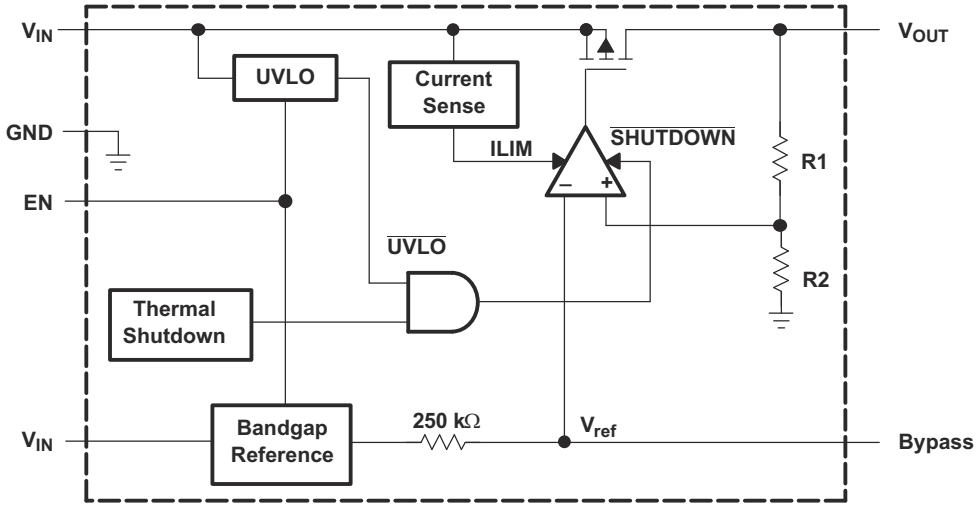


Figure 6-3. Functional Block Diagram – Fixed Version (Legacy Chip)

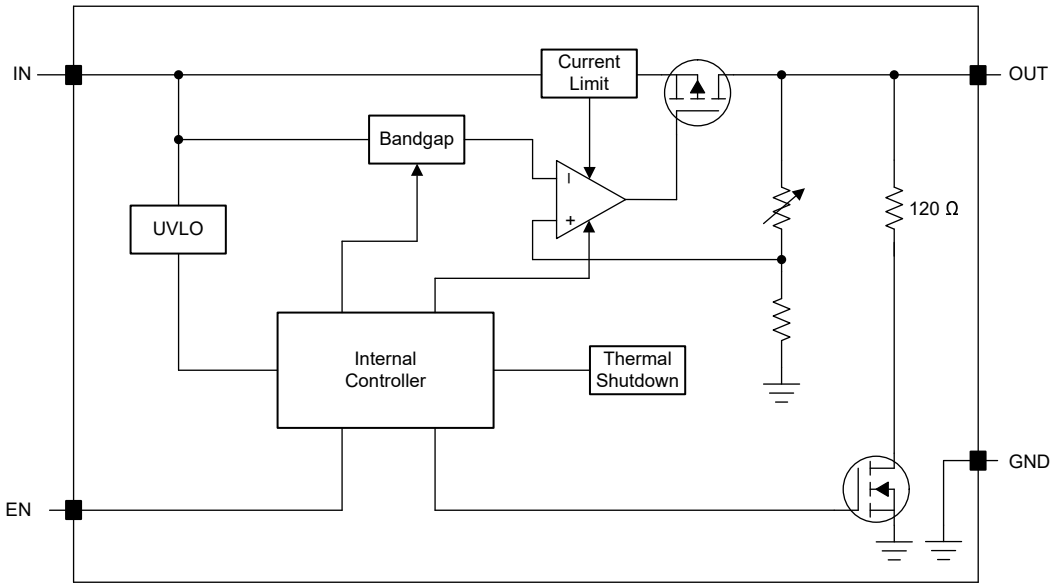


Figure 6-4. Functional Block Diagram – Fixed Version (New Chip)

6.3 Feature Description

6.3.1 Undervoltage Lockout (UVLO)

The TPS792xx uses an undervoltage lockout (UVLO) circuit that disables the output until the input voltage is greater than the rising UVLO voltage. This circuit makes sure that the device does not exhibit any unpredictable behavior when the supply voltage is lower than the operational range of the internal circuitry, $V_{IN(min)}$.

6.3.2 Shutdown

The enable pin (EN) is active high. Enable the device by forcing the EN pin to exceed $V_{EN(high)}$ (2V minimum). Turn off the device by forcing the EN pin to drop below 0.7V. If shutdown capability is not required, connect EN to IN.

6.3.3 Active Discharge (New Chip)

The device has an internal pulldown MOSFET that connects an $R_{PULLDOWN}$ resistor to ground when the device is disabled to actively discharge the output voltage. The active discharge circuit is activated by the enable pin.

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Do not rely on the active discharge circuit to discharge the output voltage after the input supply has collapsed because reverse current can possibly flow from the output to the input. This reverse current flow can cause damage to the device especially when a large output capacitor is used. Limit reverse current to no more than 5% of the device rated current for a short period of time.

6.3.4 Foldback Current Limit

The legacy chip of TPS792 features internal current limiting and thermal protection. During normal operation, the TPS792 limits output current to approximately 400mA. When current limiting engages, the output voltage scales back linearly until the overcurrent condition ends. While current limiting is designed to prevent gross device failure, care must be taken not to exceed the power dissipation ratings of the package or the absolute maximum voltage ratings of the device.

The device has an internal current limit circuit that protects the regulator during transient high-load current faults or shorting events. The current limit is a hybrid brickwall-foldback scheme. The current limit transitions from a brickwall scheme to a foldback scheme at the foldback voltage ($V_{FOLDBACK}$). In a high-load current fault with the output voltage above $V_{FOLDBACK}$, the brickwall scheme limits the output current to the current limit (I_{CL}). When the voltage drops below $V_{FOLDBACK}$, a foldback current limit activates that scales back the current as the output voltage approaches GND. When the output is shorted, the device supplies a typical current called the short-circuit current limit (I_{SC}). I_{CL} and I_{SC} are listed in the *Electrical Characteristics* table.

For this device, $V_{FOLDBACK} = 0.4 \times V_{OUT(NOM)}$.

The output voltage is not regulated when the device is in current limit. When a current limit event occurs, the device begins to heat up because of the increase in power dissipation. When the device is in brickwall current limit, the pass transistor dissipates power [$(V_{IN} – V_{OUT}) \times I_{CL}$]. When the device output is shorted and the output is below $V_{FOLDBACK}$, the pass transistor dissipates power [$(V_{IN} – V_{OUT}) \times I_{SC}$]. If thermal shutdown is triggered, the device turns off. After the device cools down, the internal thermal shutdown circuit turns the device back on. If the output current fault condition continues, the device cycles between current limit and thermal shutdown. For more information on current limits, see the *Know Your Limits* application report.

Figure 6-5 shows a diagram of the foldback current limit.

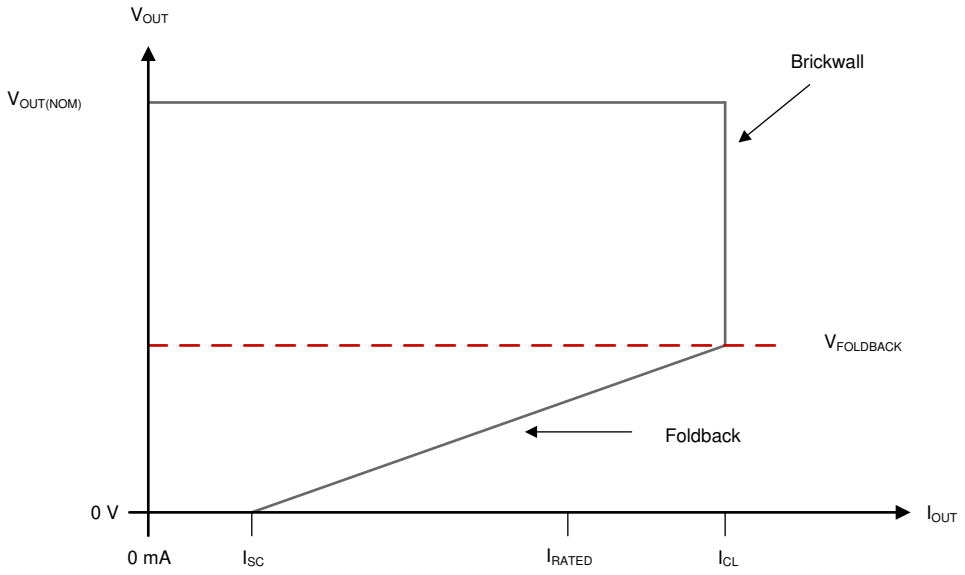


Figure 6-5. Foldback Current Limit

6.3.5 Thermal Protection

Thermal protection disables the output when the junction temperature rises to approximately 165°C, allowing the device to cool. When the junction temperature cools to approximately 140°C, the output circuitry is again enabled. Depending on power dissipation, thermal resistance, and ambient temperature, the thermal protection circuit may cycle on and off. This cycling limits regulator dissipation, protecting the device from damage as a result of overheating. Any tendency to activate the thermal protection circuit indicates excessive power dissipation or an inadequate heatsink. For reliable operation, junction temperature must be limited to 125°C maximum. To estimate the margin of safety in a complete design (including heatsink), increase the ambient temperature until the thermal protection is triggered; use worst-case loads and signal conditions.

The TPS792xx internal protection circuitry is designed to protect against overload conditions. This circuitry is not intended to replace proper heatsinking. Continuously running the TPS792xx into thermal shutdown degrades device reliability.

6.3.6 Reverse Current

The legacy chip of TPS792xx PMOS-pass transistor has a built-in back diode that conducts reverse current when the input voltage drops below the output voltage (for example, during power down). Current is conducted from the output to the input and is not internally limited. If extended reverse voltage operation is anticipated, external limiting to 5% of the rated output current is recommended.

The new chip of TPS792xx, as with most modern LDOs, excessive reverse current can damage this device.

Reverse current flows through the body diode on the pass element instead of the normal conducting channel. At high magnitudes, this current flow degrades the long-term reliability of the device as a result of one of the following conditions:

- Degradation caused by electromigration
- Excessive heat dissipation
- Potential for a latch-up condition

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Conditions where reverse current can occur are outlined in this section, all of which can exceed the absolute maximum rating of $V_{OUT} > V_{IN} + 0.3V$:

- If the device has a large C_{OUT} and the input supply collapses with little or no load current
- The output is biased when the input supply is not established
- The output is biased above the input supply

If reverse current flow is expected in the application, external protection must be used to protect the device. The image below shows one approach of protecting the device.

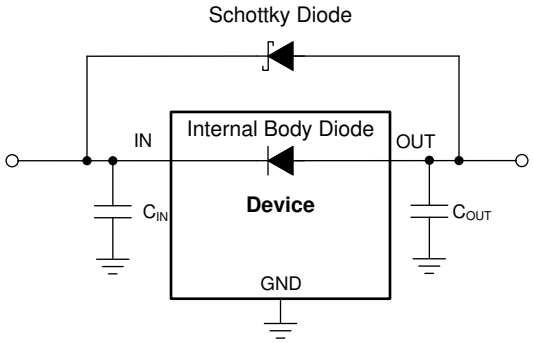


Figure 6-6. Example Circuit for Reverse Current Protection Using a Schottky Diode

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6.4 Device Functional Modes

6.4.1 Normal Operation

The device regulates to the nominal output voltage under the following conditions:

- The input voltage is at least as high as $V_{IN(min)}$.
- The input voltage is greater than the nominal output voltage added to the dropout voltage.
- The enable voltage is greater than $V_{EN(min)}$.
- The output current is less than the current limit.
- The device junction temperature is less than the maximum specified junction temperature.

6.4.2 Dropout Operation

If the input voltage is lower than the nominal output voltage plus the specified dropout voltage, but all other conditions are met for normal operation, the device operates in dropout mode. In this mode of operation, the output voltage is the same as the input voltage minus the dropout voltage. The transient performance of the device is significantly degraded because the pass device is in the linear region and no longer controls the current through the LDO. Line or load transients in dropout can result in large output voltage deviations.

6.4.3 Disabled

The device is disabled under the following conditions:

- The enable voltage is less than the enable falling threshold voltage or has not yet exceeded the enable rising threshold.
- The device junction temperature is greater than the thermal shutdown temperature.
- The input voltage is less than $UVLO_{falling}$.

Table 6-1 lists the conditions that lead to the different modes of operation.

Table 6-1. Device Functional Mode Comparison

OPERATING MODE	PARAMETER			
	V_{IN}	V_{EN}	I_{OUT}	T_J
Normal mode	$V_{IN} > V_{OUT(nom)} + V_{DO}$ and $V_{IN} > V_{IN(min)}$	$V_{EN} > V_{EN(high)}$	$I_{OUT} < I_{LIM}$	$T_J < 125°C$
Dropout mode	$V_{IN(min)} < VIN < V_{OUT(nom)} + V_{DO}$	$V_{EN} > V_{EN(high)}$	—	$T_J < 125°C$
Disabled mode (any true condition disables the device)	$V_{IN} < UVLO_{falling}$	$V_{EN} < V_{EN(low)}$	—	$T_J > 165°C$(1)

(1) Approximate value for thermal shutdown

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7 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

7.1 Application Information

The TPS792xx family of LDO regulators has been optimized for use in noise-sensitive battery-operated equipment. The device features extremely low dropout voltages, high PSRR, low output noise, low quiescent current, and enable-input to reduce supply currents to less than 1µA when the regulator is turned off.

7.1.1 Adjustable Operation

The output voltage of the TPS792xx01 adjustable regulator is programmed using an external resistor divider as shown in the image below. The output voltage is calculated using the equation below:

$$V_{OUT} = V_{REF} \times \left(1 + \frac{R_1}{R_2}\right) \quad (1)$$

where:

- V_{REF} = 1.2246V typ (the internal reference voltage)

Resistors R_1 and R_2 must be selected for approximately 50µA divider current. Lower value resistors can be used for improved noise performance, but the solution consumes more power. Higher resistors values can cause accuracy issues and other problems. The recommended design procedure is to choose R_2 = 30.1kΩ to set the divider current at 50µA, C_{FF} = 15pF for stability, and then calculate R_1 using the equation below:

$$R_1 = \left(\frac{V_{OUT}}{V_{REF}} - 1\right) \times R_2 \quad (2)$$

To improve the stability of the adjustable version, place a small compensation capacitor between OUT and FB. For output voltages less than 1.8V, the value of this capacitor must be 100pF. For output voltages greater than 1.8V, the approximate value of this capacitor can be calculated as shown in the equation below:

$$C_{FF} = \frac{(3 \times 10^{-7}) \times (R_1 + R_2)}{(R_1 \times R_2)} \quad (3)$$

The suggested value of this capacitor for several resistor ratios is shown in the table in the image below. If this capacitor is not used (such as in a unity-gain configuration) or if an output voltage less than 1.8V is chosen, then the minimum recommended output capacitor is 4.7µF instead of 2.2µF.

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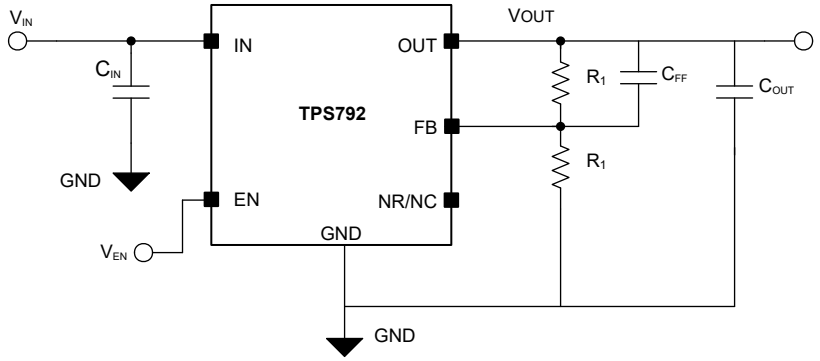


Table 7-1. OUTPUT VOLTAGE PROGRAMMING GUIDE

OUTPUT VOLTAGE	R_1	R_2	C_{FF}
1.22V	Short	Open	0pF
2.5V	31.6kΩ	30.1kΩ	22pF
3.3V	51kΩ	30.1kΩ	15pF
3.6V	59kΩ	30.1kΩ	15pF

Figure 7-1. TPS792xx01 Adjustable LDO Regulator Programming

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7.1.2 Exiting Dropout

Some applications have transients that place the LDO into dropout, such as slower ramps on V_{IN} during start-up. As with other LDOs, the output can overshoot on recovery from these conditions. A ramping input supply causes an LDO to overshoot on start-up, as shown in Figure 7-2, when the slew rate and voltage levels are in the correct range. Use an enable signal to avoid this condition.

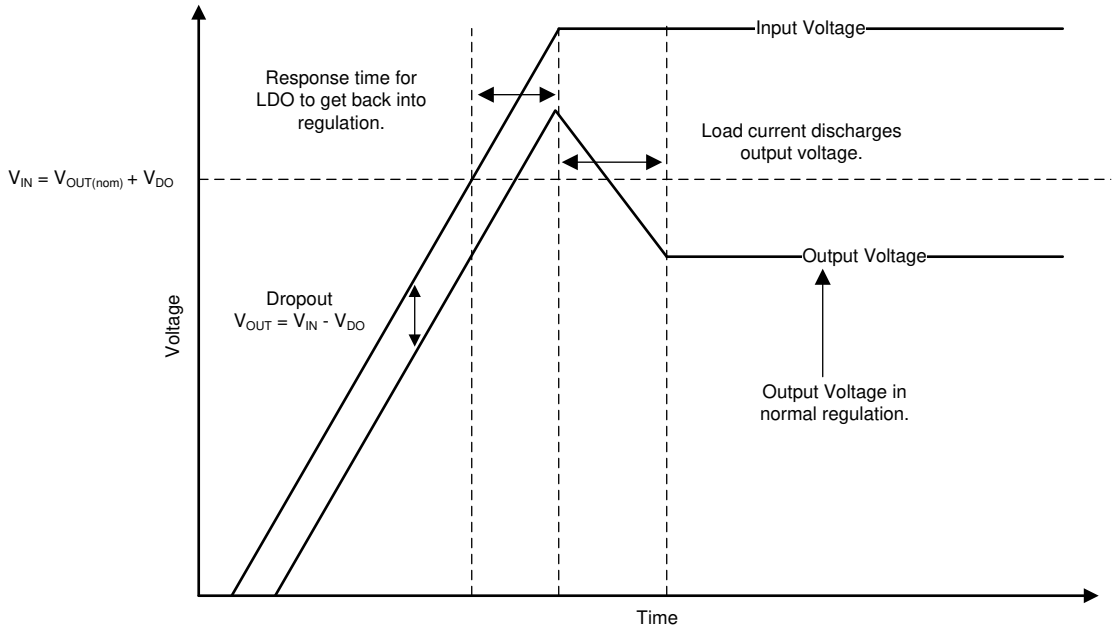


Figure 7-2. Start-Up Into Dropout

Line transients out of dropout can also cause overshoot on the output of the regulator. These overshoots are caused by the error amplifier having to drive the gate capacitance of the pass element and bring the gate back to the correct voltage for proper regulation. Figure 7-3 illustrates what is happening internally with the gate voltage and how overshoot can be caused during operation. When the LDO is placed in dropout, the gate voltage (V_{GS}) is pulled all the way down to ground to give the pass device the lowest on-resistance as possible. However, if a line transient occurs when the device is in dropout, the loop is not in regulation and can cause the output to overshoot until the loop responds and the output current pulls the output voltage back down into regulation. If these transients are not acceptable, then continue to add input capacitance in the system until the transient is slow enough to reduce the overshoot.

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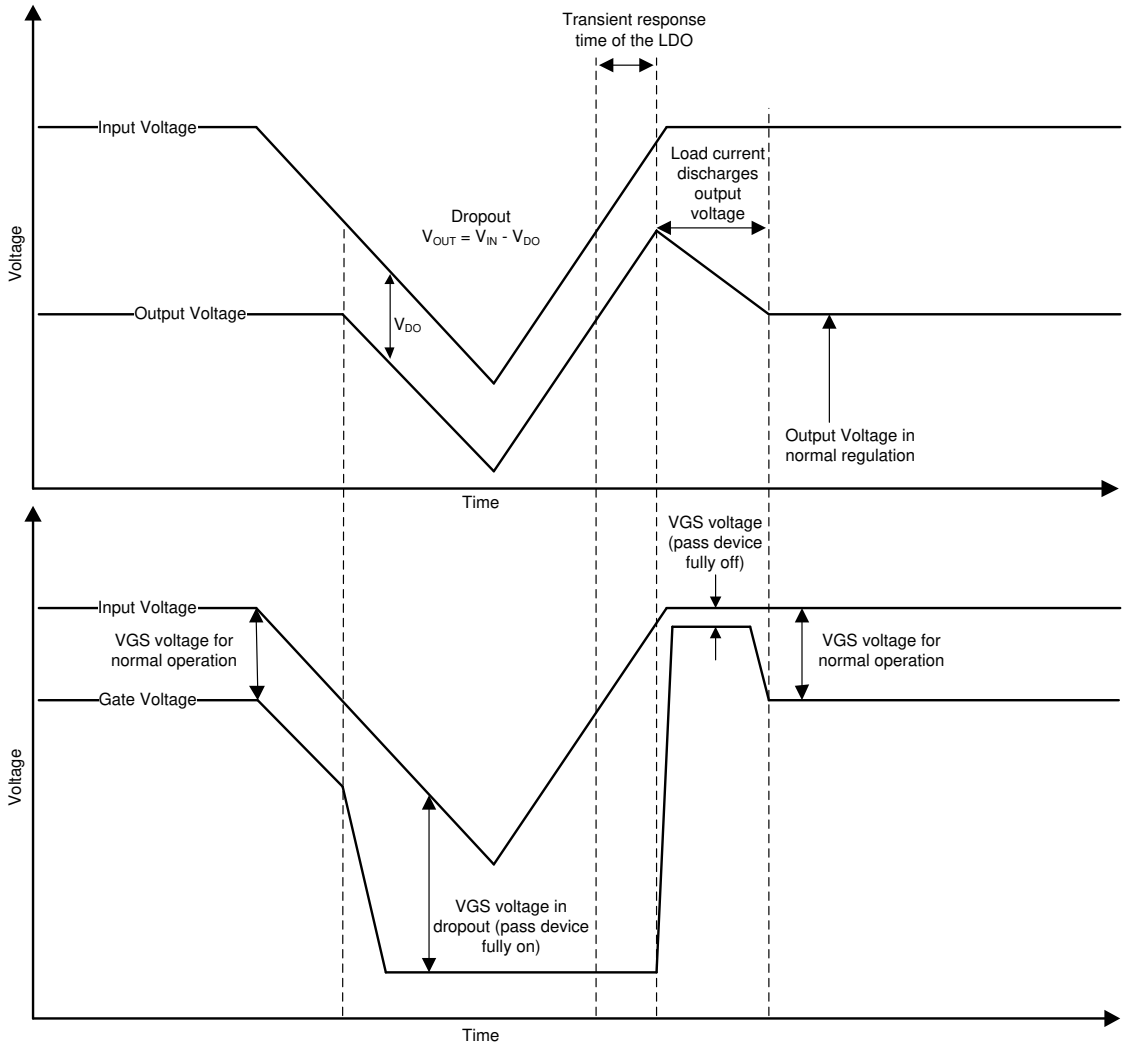


Figure 7-3. Line Transients From Dropout

7.2 Typical Application

A typical application circuit is shown in Figure 7-4.

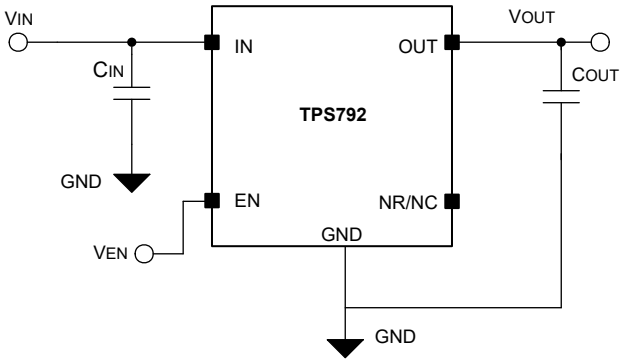


Figure 7-4. Typical Application Circuit

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7.2.1 Design Requirements

Table 7-2 lists the design requirements.

Table 7-2. Design Parameters

PARAMETER	DESIGN REQUIREMENTS
Input voltage	3V – 4V (lithium ion battery)
Output voltage	2.8V
DC output current	10mA
Peak output current	75mA
Maximum ambient temperature	65°C

7.2.2 Detailed Design Procedure

7.2.2.1 Capacitor Recommendations

Low equivalent series resistance (ESR) capacitors must be used for the input, output, noise reduction, and bypass capacitors. Ceramic capacitors with X7R and X5R dielectrics are preferred. These dielectrics offer more stable characteristics. Ceramic X7R capacitors offer improved over-temperature performance, while ceramic X5R capacitors are more cost-effective and are available in higher values.

7.2.2.2 Input and Output Capacitor Requirements

A 0.1µF or larger ceramic input bypass capacitor, connected between IN and GND and located close to the legacy chip of TPS792xx, is required for stability and improves transient response, noise rejection, and ripple rejection. A 1µF or larger ceramic input bypass capacitor, connected between IN and GND and located close to the new chip of TPS792xx, is required for stability and improves transient response, noise rejection, and ripple rejection. A higher-value input capacitor can be necessary if large, fast-rise-time load transients are anticipated or the device is located several inches from the power source.

Like most low-dropout regulators, the TPS792xx requires an output capacitor connected between OUT and GND to stabilize the internal control loop. The minimum recommended capacitance is 2.2µF. Any 2.2µF or larger ceramic capacitor is suitable, provided the capacitance does not vary significantly over temperature. If load current is not expected to exceed 100 mA, a 1.0µF ceramic capacitor can be used. If a feed-forward capacitor is not used (such as in a unity-gain configuration) or if an output voltage less than 1.8V is chosen, then the minimum recommended output capacitor is 4.7µF instead of 2.2µF. The table below lists the recommended output capacitor sizes for several common configurations.

Table 7-3. Output Capacitor Sizing

Condition	C_{OUT} (µF)
V_{OUT} < 1.8V or C_{FF} = 0nF	4.7
V_{OUT} > 1.8V, I_{OUT} > 100mA	2.2
V_{OUT} > 1.8V, I_{OUT} < 100mA	1

7.2.2.3 Noise Reduction and Feed-Forward Capacitor Requirements

The internal voltage reference is a key source of noise in an LDO regulator. The legacy chip of TPS792xx has an NR pin which is connected to the voltage reference through a 250kΩ internal resistor. The 250kΩ internal resistor, in conjunction with an external bypass capacitor connected to the NR pin, creates a low-pass filter to reduce the voltage reference noise and, therefore, the noise at the regulator output. In order for the regulator to operate properly, the current flow out of the NR pin must be at a minimum, because any leakage current creates an IR drop across the internal resistor, thus creating an output error. Therefore, the bypass capacitor must have minimal leakage current. The bypass capacitor must be no more than 0.1µF to verify that the capacitor is fully charged during the quick-start time provided by the internal switch in the *Functional Block Diagrams*.

A feed-forward capacitor is recommended when using the adjustable version, to improve the stability of the device. If R_2 = 30.1kΩ, set C_1 to 15pF for optimal performance. For voltages less than 1.8V, the value of this

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capacitor must be 100pF. For voltages greater than 1.8V, calculate the approximate value of this capacitor as given in the *Functional Block Diagrams*.

7.2.3 Application Curves

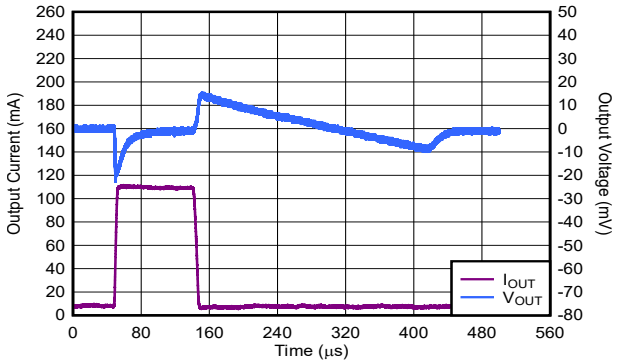


Figure 7-5. TPS792xx Load Transient Response

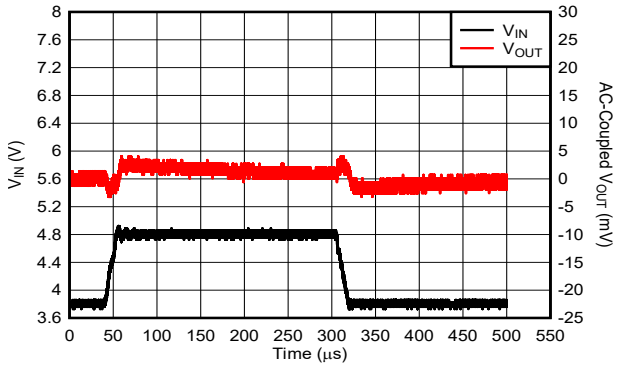


Figure 7-6. TPS792xx Line Transient Response

7.3 Power Supply Recommendations

This device is designed to operate from an input voltage supply range from 2.7V to 5.5V. The input voltage range must provide adequate headroom for the device to have a regulated output. This input supply must be well-regulated and stable. A 0.1µF input capacitor is required for stability (legacy chip) or a 1µF (new chip); if the input supply is noisy, additional input capacitors with low ESR can help improve the output noise performance.

7.4 Layout

7.4.1 Layout Guidelines

Layout is a critical part of good power-supply design. There are several signal paths that conduct fast-changing currents or voltages that can interact with stray inductance or parasitic capacitance to generate noise or degrade the power-supply performance. To help eliminate these problems, the IN pin should be bypassed to ground with a low ESR ceramic bypass capacitor with an X5R or X7R dielectric.

Equivalent series inductance (ESL) and equivalent series resistance (ESR) must be minimized to maximize performance and ensure stability. Every capacitor (C_{IN}, C_{OUT}, C_{NR}, C_{FF}) must be placed as close as possible to the device and on the same side of the PCB as the regulator itself. Do not place any of the capacitors on the opposite side of the PCB from where the regulator is installed. The use of vias and long traces is strongly discouraged because these circuits may impact system performance negatively, and even cause instability.

7.4.1.1 Board Layout Recommendations to Improve PSRR and Noise Performance

To improve ac measurements like PSRR, output noise, and transient response, it is recommended that the board be designed with separate ground planes for V_{IN} and V_{OUT}, with each ground plane connected only at the GND pin of the device. In addition, the ground connection for the bypass capacitor should connect directly to the GND pin of the device.

7.4.1.2 Power Dissipation and Junction Temperature

Specified regulator operation is to a junction temperature of 125°C; the maximum junction temperature should be restricted to 125°C under normal operating conditions. This restriction limits the power dissipation the regulator can handle in any given application. To ensure the junction temperature is within acceptable limits, calculate the maximum allowable dissipation, $P_{D(max)}$, and the actual dissipation, P_D, which must be less than or equal to $P_{D(max)}$.

The maximum power dissipation limit is determined using Equation 4.

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$$P_{D(max)} = \frac{T_J max - T_A}{R_{\theta JA}} \quad (4)$$

where

- $T_J$max = Maximum allowable junction temperature
- $R_{\theta JA}$ = Thermal resistance, junction to ambient, for the package, see the Thermal Information table.
- T_A = Ambient temperature

The regulator dissipation is calculated using the below equation.

$$P_D = (V_I - V_O) \times I_O \quad (5)$$

Power dissipation resulting from quiescent current is negligible. Excessive power dissipation triggers the thermal protection circuit.

7.4.2 Layout Example

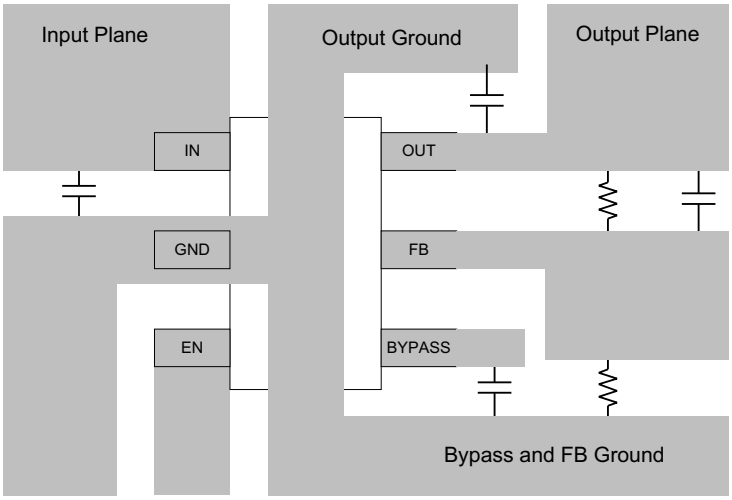


Figure 7-7. Layout Example (DBV 6-Pin Package)

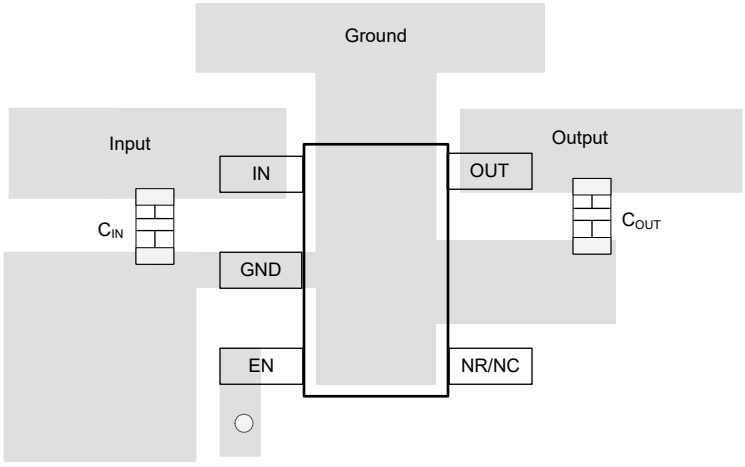


Figure 7-8. Layout Example (DBV 5-Pin Package, New Chip)

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8 Device and Documentation Support

8.1 Device Support

8.1.1 Development Support

8.1.1.1 Evaluation Modules

Several evaluation modules (EVMs) are available to assist in the initial circuit performance evaluation using the TPS793:

- TPS79301EVM
- TPS793285YEQEVM
- TPS79328EVM

These EVMs can be requested at the Texas Instruments website through the device product folders or purchased directly from the TI eStore.

8.1.1.2 Spice Models

Computer simulation of circuit performance using SPICE is often useful when analyzing the performance of analog circuits and systems. A SPICE model for the TPS793 is available through the product folders under *Tools & Software*.

8.1.2 Device Nomenclature

Table 8-1. Ordering Information

PRODUCT(1) (2)	V_{OUT}
TPS792xx**xx** ***yyy*M3** *z*	**XX(X)** is the nominal output voltage (for example, 28 = 2.8 V; 285 = 2.85 V; 01 = adjustable version). **YYY** is the package designator. **M3** is a suffix designator for the devices that only use the latest manufacturing flow (CSO:RFB). Devices without this suffix can ship with the legacy chip (CSO:DLN) or the new chip (CSO:RFB). The reel packaging label provides CSO information to distinguish which chip is being used. **Z** is the package quantity. R is for reel (3000 pieces), T is for tape (250 pieces).

(1) For the most current package and ordering information see the Package Option Addendum at the end of this document, or visit the device product folder on www.ti.com.
(2) Output voltages from 1.2 V to 4.8 V in 50-mV increments are available. Contact the factory for details and availability.

8.2 Documentation Support

8.2.1 Related Documentation

For related documentation see the following:

- Texas Instruments, *Using New Thermal Metrics* application note
- Texas Instruments, *Pros and Cons of Using a Feedforward Capacitor with a Low-Dropout Regulator* application note
- Texas Instruments, *TPS79301EVM, TPS79328EVM LDO Linear Regulator Evaluation Module* EVM user's guide

8.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

8.4 Support Resources

TI E2E™ support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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8.6 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

8.7 Glossary

TI Glossary This glossary lists and explains terms, acronyms, and definitions.

9 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision D (December 2024) to Revision E (January 2025)	Page
• Added *New Chip* to *Layout Example (DBV 5-Pin Package)* figure caption	25

Changes from Revision C (December 2024) to Revision D (December 2024)	Page
• Added *Layout Example (DBV 5-Pin Package)* figure	25

Changes from Revision B (May 2002) to Revision C (December 2024)	Page
• Updated the numbering format for tables, figures, and cross-references throughout the document	1
• Changed entire document to align with current family format	1
• Added M3 devices to document	1
• Added NC/NR pin	1
• Updated Pin Description table to include new chip and legacy chip descriptions	1
• Added suggestion to look at TPS7A20 for lower noise performance	1

10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TPS79201DBVR	Active	Production	SOT-23 (DBV) | 6	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	PEVI
TPS79201DBVR.A	Active	Production	SOT-23 (DBV) | 6	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	PEVI
TPS79201DBVRG4	Active	Production	SOT-23 (DBV) | 6	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	PEVI
TPS79201DBVRG4.A	Active	Production	SOT-23 (DBV) | 6	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	PEVI
TPS79201DBVRM3	Active	Production	SOT-23 (DBV) | 6	3000 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	PEVI
TPS79225DBVR	Active	Production	SOT-23 (DBV) | 5	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	PEXI
TPS79225DBVR.A	Active	Production	SOT-23 (DBV) | 5	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	PEXI
TPS79225DBVT	Obsolete	Production	SOT-23 (DBV) | 5	-	-	Call TI	Call TI	-40 to 125	PEXI
TPS79228DBVR	Active	Production	SOT-23 (DBV) | 5	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	PEWI
TPS79228DBVR.A	Active	Production	SOT-23 (DBV) | 5	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	PEWI
TPS79228DBVT	Obsolete	Production	SOT-23 (DBV) | 5	-	-	Call TI	Call TI	-40 to 125	PEWI
TPS79230DBVR	Active	Production	SOT-23 (DBV) | 5	3000 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	PEYI
TPS79230DBVR.A	Active	Production	SOT-23 (DBV) | 5	3000 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	PEYI
TPS79230DBVRG4	Active	Production	SOT-23 (DBV) | 5	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	PEYI
TPS79230DBVRG4.A	Active	Production	SOT-23 (DBV) | 5	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	PEYI
TPS79230DBVT	Obsolete	Production	SOT-23 (DBV) | 5	-	-	Call TI	Call TI	-40 to 125	PEYI

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

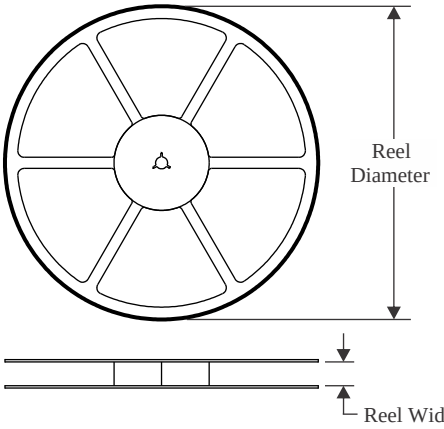
Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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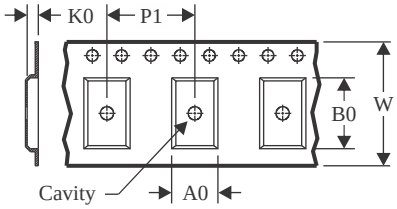
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TAPE AND REEL INFORMATION

REEL DIMENSIONS

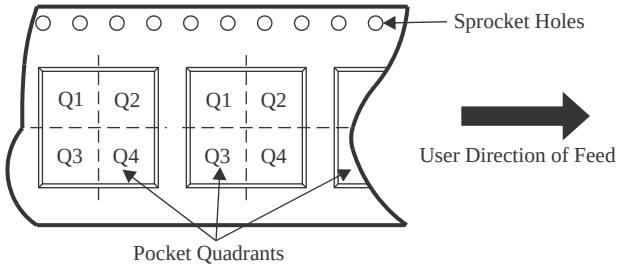


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

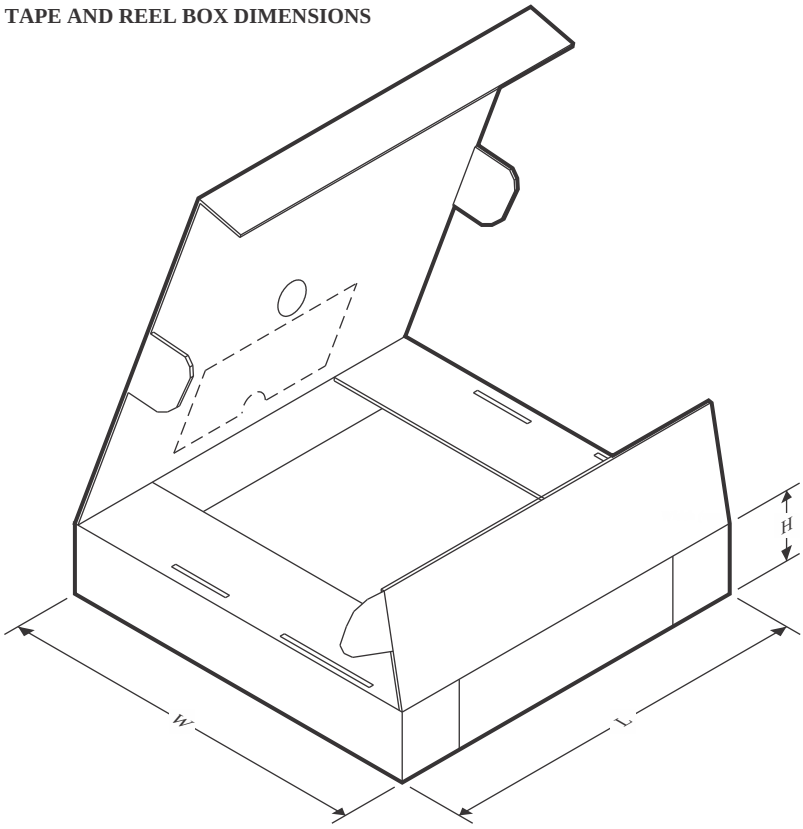
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS79201DBVR	SOT-23	DBV	6	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS79201DBVRG4	SOT-23	DBV	6	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS79201DBVRM3	SOT-23	DBV	6	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS79225DBVR	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS79228DBVR	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS79230DBVR	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS79230DBVRG4	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

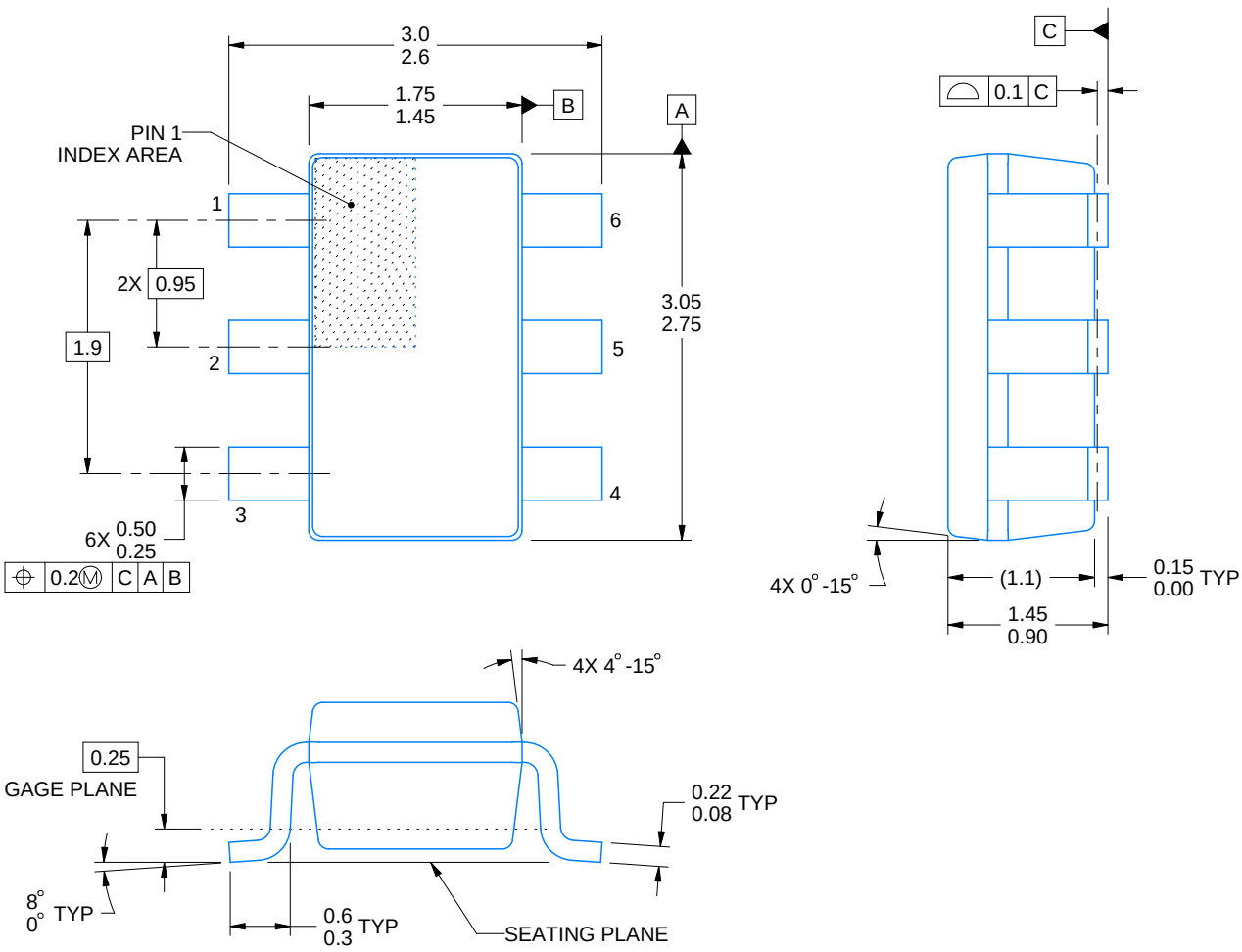
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS79201DBVR	SOT-23	DBV	6	3000	180.0	180.0	18.0
TPS79201DBVRG4	SOT-23	DBV	6	3000	180.0	180.0	18.0
TPS79201DBVRM3	SOT-23	DBV	6	3000	210.0	185.0	35.0
TPS79225DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
TPS79228DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
TPS79230DBVR	SOT-23	DBV	5	3000	210.0	185.0	35.0
TPS79230DBVRG4	SOT-23	DBV	5	3000	180.0	180.0	18.0

PACKAGE OUTLINE

DBV0006A

SOT-23 - 1.45 mm max height

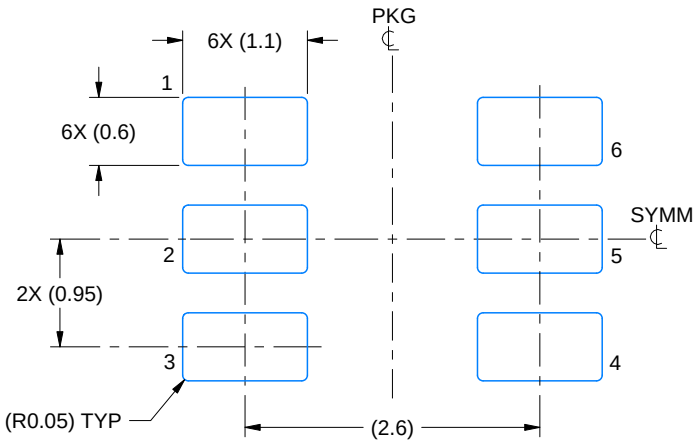
SMALL OUTLINE TRANSISTOR



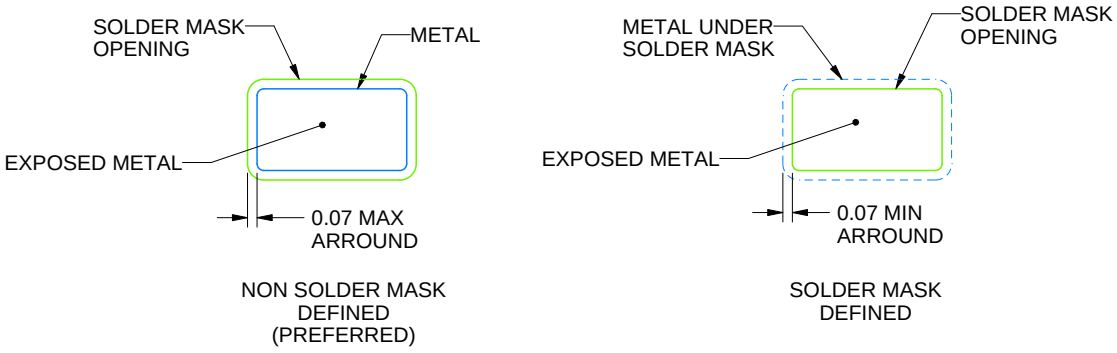
4214840/G 08/2024

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.25 per side.
4. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
5. Refernce JEDEC MO-178.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X

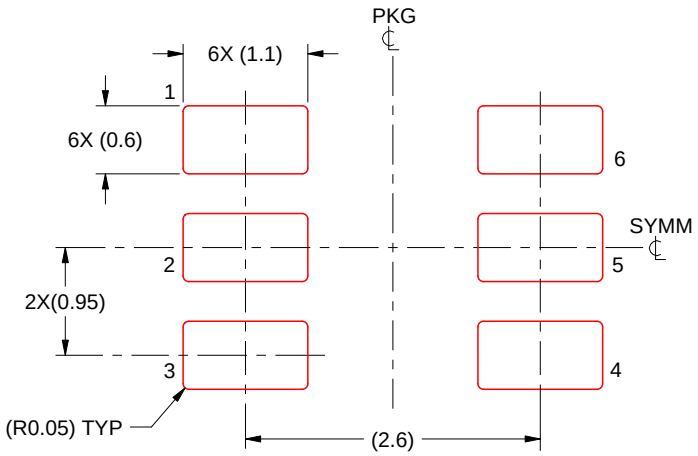


SOLDER MASK DETAILS

4214840/G 08/2024

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

4214840/G 08/2024

NOTES: (continued)

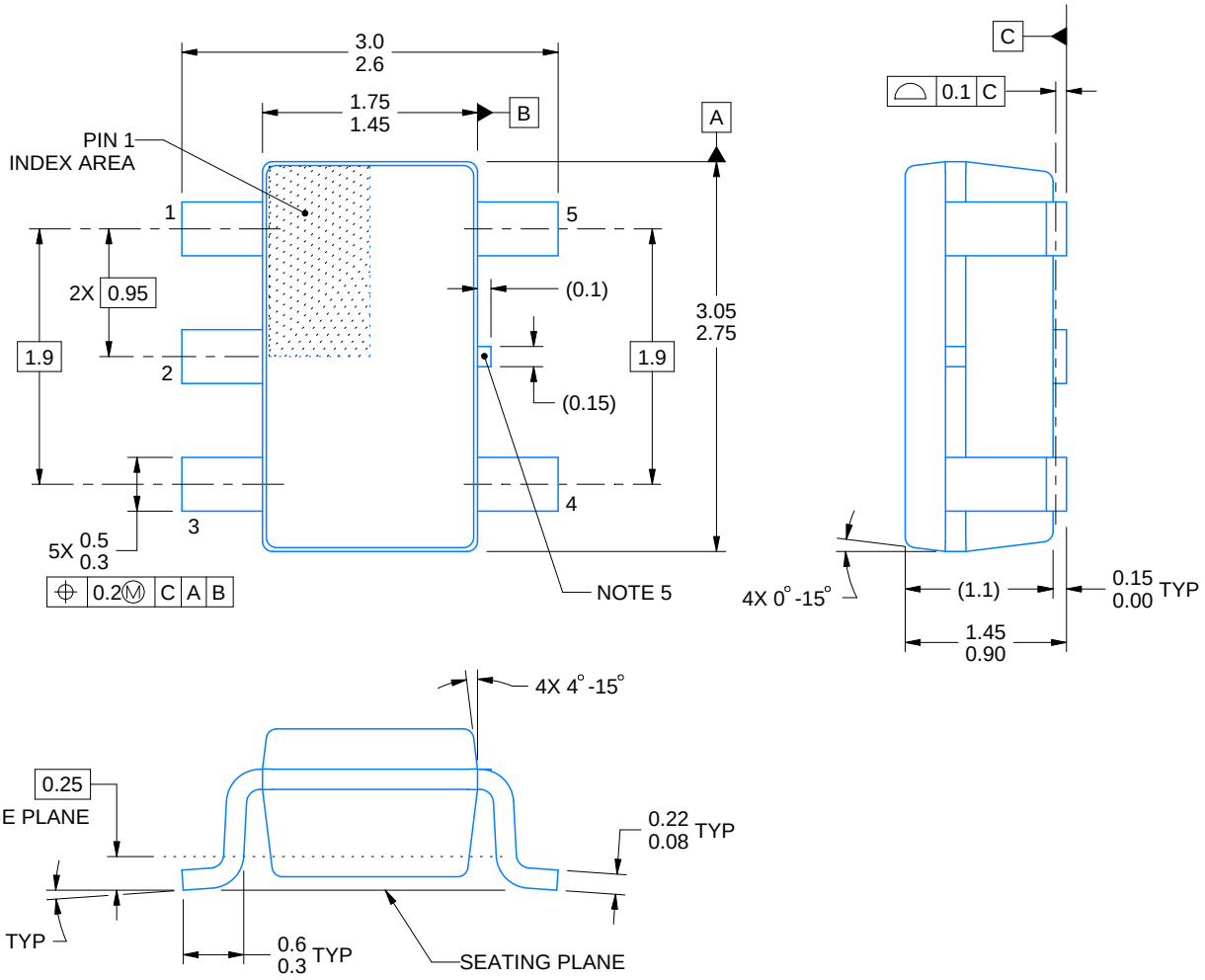
8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

PACKAGE OUTLINE

DBV0005A

SOT-23 - 1.45 mm max height

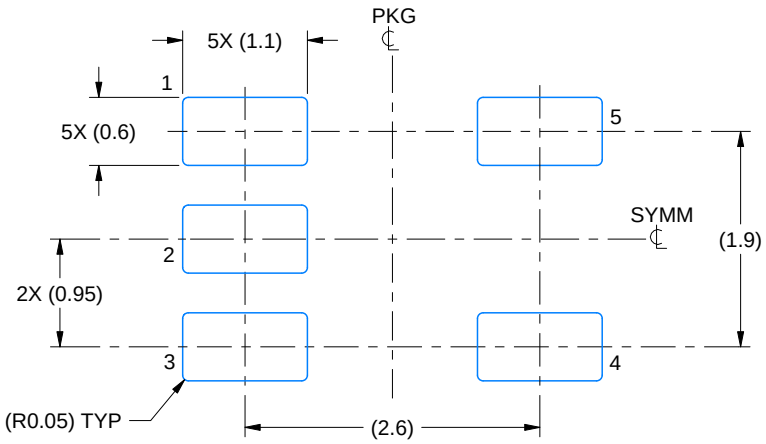
SMALL OUTLINE TRANSISTOR



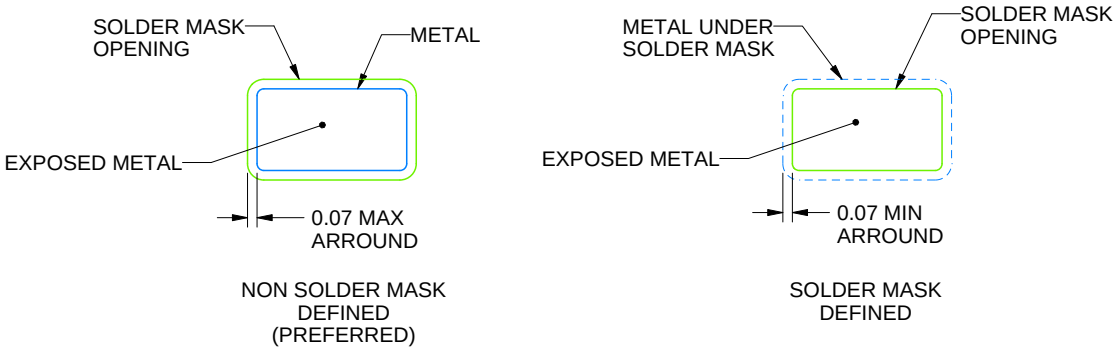
4214839/K 08/2024

NOTES:

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2. This drawing is subject to change without notice.
3. Refernce JEDEC MO-178.
4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.
5. Support pin may differ or may not be present.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X

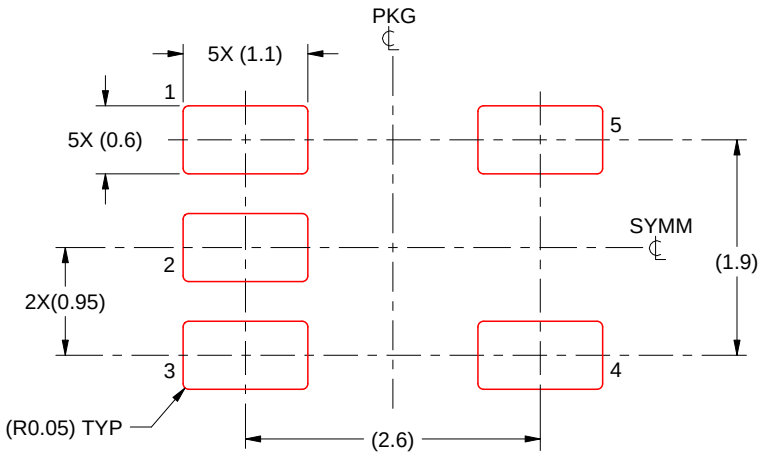


SOLDER MASK DETAILS

4214839/K 08/2024

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

4214839/K 08/2024

NOTES: (continued)

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9. Board assembly site may have different recommendations for stencil design.

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Last updated 10/2025

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